AND THEIR CONVERSION TO 2,5-DIHALO DERIVATIVES

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<u>Abstract</u> - 2,5-Disilylated thiophenes were prepared and readily oxidized with mchloroperbenzoic acid (m-CPBA) to give the corresponding 1,1-dioxides. The thiophene dioxide was converted to 2,5-dihalogenothiophene dioxides with halogenating agents.

A few thiophene monooxides have been successfully isolated,¹ while dioxides bearing suitable substituents are isolated as stable compounds.² We have intended to explore the utilization of thiophene derivatives for organic synthesis and found that 2,5-bistrimethylsilyl and the related silyl derivatives were oxidized readily to give the corresponding sulfones. This paper reports the preparation and reactions of several silylated thiophene derivatives including silicon-bridged macrocycles.

2,5-Disilylthiophenes (1a-c) were prepared by the known method³ using 2 equivalents of BuLi and subsequent treatment of the dilithiothiophene with 2 equivalents of silyl chlorides. Then these were treated with *m*-CPBA to afford the corresponding sulfones (2a-c) in good yields (Scheme 1).⁴



iii. m-CPBA/CH2Cl2/room temperature/1 day

In a typical experiment, 2,5-bis(trimethylsilyl)thiophene (1a) (2.32 g, 10 mmol) was oxidized with *m*-CPBA (6.16 g, 25 mmol) in CH₂Cl₂ (200 ml) for 24 h at room temperature. After usual work-up and column chromatography using silica gel and hexane-CH₂Cl₂ (1:1) as an eluent, the crude crystals separated were recrystallized from hexane. 2,5-Bis(trimethylsilyl)thiophene 1,1-dioxide (2a) was obtained in 91% yield (Scheme 1). X-ray crystallographic analysis of 2a reveals that it is a nearly planar molecule having a C_{2v} symmetry bisecting the SO₂ and the C₃-C₄ bond.⁵

When thiophene was treated with 1 equivalent of BuLi and then with 0.5 equivalent of dichlorodimethylsilane, dimethyldi(2-thienyl)silane (3) was obtained in 74% yield. 3 was treated with 2 equivalents of lithium diisopropylamide (LDA) and then with trimethylsilyl chloride affording dimethyl-bis-(5-trimethylsilyl-2-thienyl)silane (4) in 76% yield. In the oxidation of 4 with 1 equivalent of *m*-CPBA, one thiophene ring was preferentially oxidized to afford only the mono-sulfone (5) in 36% yield. For further addition of *m*-CPBA, the corresponding mono-sulfone (5) and bis-sulfone (6) were obtained in 21% and 41% yields, respectively.



Scheme 2. i. 1 eq. BuLi/THF/N₂/-20°C/1 h; ii. 0.5 eq. Me₂SiCl₂/-20°C/1 h; iii. 2 eq. LDA/THF/N₂/-20°C/1 h; iv. 2 eq. Me₃SiCl/-20°C/1 h; v. 1 eq. Me₂SiCl₂/-20°C/1 h; vi. *m*-CPBA/CH₂Cl₂/room temperature/1 day

When the reaction of 3 was conducted by using 2 equivalents of LDA and 1 equivalent of dichlorodimethylsilane at -20 °C in THF for 2 h, macrocyclic compounds (7) and (8) were obtained without using high dilution technique. The products were separated by column chromatography (silica gel) and then

purified by preparative liquid chromatography affording 7 and 8 in 17 and 15% yields, respectively.⁶ Kauffman *et al.* reported the preparation of 7 in 16% yield by similar procedure but using BuLi instead of LDA as a base.⁷ However, judging from the physical and spectroscopic evidence, their product seems to be a mixture of 7 and 8.

In order to convert these 1,1-dioxides to other thiophene derivatives, 2a was treated with bromine or iodine in the presence of AgBF4 in CH₂Cl₂ at 0 °C for 1 h to afford the corresponding bromo (9) and iodo (10) derivatives in 72 and 97 % yields, respectively.^{8,9} When the reaction was carried out in the absence of AgBF4, iodine did not react at all even changing the reaction conditions while bromine reacted with 2a to give 9 in 47 % yield. But the reaction required high temperature (50 °C) and longer reaction time (72 h). The results are shown in Table 1.



Run	X ₂	Equiv.	Solvent	Temp. (°C)	Time (h)	Yield (%)
1	Br ₂ ,AgBF ₄ ^{a)}	2	CH ₂ Cl ₂	0	1	72
2	l ₂ ,AgBF ₄ ^{a)}	2	CH ₂ Cl ₂	0	1	97
3	Br ₂	3	CCl4	50	72	47
4	2	3	CCI4	reflux	168	0

Table 1. Preparation of 2,5-Dihalogenated Thiophene 1,1-Dioxides

a) 3 eq. of AgBF₄ was used.

Introduction of silyl groups at the 2,5-positions in thiophene provides advantages not only for protection of the sulfonyl group from dimerization but also masking of the 2,5-positions of the thiophene ring to which halogen atoms can readily be introduced and hence promises to be a convenient method for preparation of various thiophene derivatives.

Further investigations on these thiophene dioxides and their derivatives are in progress.

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- 3. (a). H. Sakurai, S. Hoshi, A. Kamiya, A. Hosomi, and C. Kabuto, <u>Chem. Lett.</u>, 1986, 1781; (b). For review, E. Block and M. Aslam, <u>Tetrahedron</u>, 1988, <u>44</u>, 281.
- 4. 2a: Yield, 91%; mp 153-154 °C (hexane); ¹H-nmr (CDCl₃) δ 6.74 (s, 2H, ThH), 0.34 (s, 18H, Me); ¹³C-nmr (CDCl₃) δ 150.6, 135.9, -1.74; FT-ir (KBr) 1282, 1129 cm⁻¹ (SO₂). Anal. Calcd for C₁₀H₂₀O₂SSi₂: C, 46.11; H, 7.74. Found: C, 46.05; H, 7.58; 2b: Yield, 84%; mp 62-64 °C (hexane); ¹H-nmr (CDCl₃) δ 7.57-7.25 (m, 10H, ArH), 6.54 (s, 2H, ThH), 0.63 (s, 12H, Me); ¹³C-nmr (CDCl₃) δ 149.6, 137.5, 134.5 134.0, 130.1, 128.1, -3.29; FT-ir (KBr) 1284, 1131 cm⁻¹ (SO₂). Anal. Calcd for C₂₀H₂₄O₂SSi₂: C, 62.50; H, 6.25. Found: C, 62.41; H,6.24; 2c: Yield, 80%; mp 154-155 °C (hexane); ¹H-nmr (CDCl₃) δ 6.80 (s, 2H, ThH), 0.99 (s, 18H, *t*-Bu), 0.31(s, 12H, Me); ¹³C-nmr (CDCl₃) δ 149.1, 137.2, 26.3, 17.2, -6.02; FT-ir (KBr) 1284, 1127 cm⁻¹ (SO₂). Anal. Calcd for C₁₆H₃₂O₂SSi₂: C, 61.54; H, 10.09. Found: C, 61.35; H, 10.18.
- X-ray crystallographic analysis: bond lengths (Å); C-S:1.761, C2-C3(C4-C5):1.323, C3-C4:1.480. bond angles; O-S-O:113.4°, C2-S-C5:96.1°, C2-S-O:111.5°.
- 6. 7: mp 278-279 °C (lit.⁸ 224-226 °C); ¹H-nmr (CDCl₃) δ 7.39 (s, 8H, ThH), 0.63 (s, 24H, Me); ¹³C-nmr (CDCl₃) δ 144.8, 135.5, -0.34; ms (m/z) 560 (M⁺). Anal. Calcd for C₂₄H₃₂S₄Si₄: C, 51.38; H, 5.71. Found: C, 51.38; H, 5.61; 8: mp 252-253 °C (benzene-hexane); ¹H-nmr (CDCl₃) δ 7.34(s, 12H, ThH), 0.63 (s, 36H, Me); ¹³C-nmr (CDCl₃) δ 143.8, 136.6, -0.02; ms (m/z) 840 (M⁺). Anal. Calcd for C₃₆H₄₈S₆Si₆: C, 51.38; H, 5.71. Found: C, 51.41; H, 5.73.
- 7. T. Kauffman and H. H. Kniese, Tetrahedron Lett., 1973, 4043.
- 8. The compound (9) has been synthesized by the oxidation of 2,5-dibromothiophene.^{2c}
- 9. 10: mp 147 -150 °C (decomp.) (dichloromethane-hexane); ¹H-nmr (CDCl₃) δ 6.87(s, 2H); ¹³C-nmr (CDCl₃) δ 128.3, 119.3; ms (m/z) 368 (M⁺); FT-ir (KBr) 1303, 1147 cm⁻¹(SO₂). Anal. Calcd for C4H₂O₂I₂S: C, 13.04; H, 0.74. Found: C, 13.37; H, 0.74.